

isc Silicon NPN Darlington Power Transistor

BD643

DESCRIPTION

- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= 45V(Min)
- High DC Current Gain
- : h_{FE}= 750(Min) @I_C= 3A
- Low Saturation Voltage
- Complement to Type BD644
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

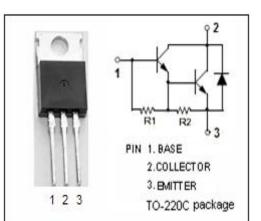
• Designed for use as complementary AF push-pull output stage applications

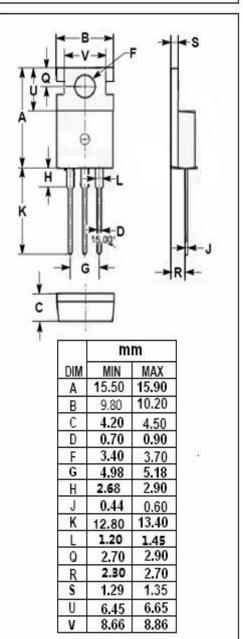
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	8	А
I _{CP}	Collector Current-Peak	12	А
I _B	Base Current-Continuous	0.3	А
Pc	Collector Power Dissipation @ T _a =25°C	2	W
	Collector Power Dissipation @ T _C =25°C	62.5	vv
TJ	Junction Temperature 150		°C
T _{stg}	Storage Temperature Range	-65~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
R _{th j-c}	Thermal Resistance, Junction to Case	2	°C/W	
R _{th j-a}	Thermal Resistance, Junction to Ambient	70	°C/W	





isc website: www.iscsemi.com

¹ isc & is



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	45			V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	I _C = 4Α; I _B = 16mΑ			2.0	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 5Α; I _B = 50mA			2.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 3A ; V _{CE} = 3V			2.5	V
Ісво	Collector Cutoff Current	V_{CB} = 45V; I _E = 0			0.2	- mA
		V _{CB} = 30V; I _E = 0; T _C = 150℃			2.0	
I _{CEO}	Collector Cutoff Current	V _{CE} = 25V; I _B = 0			0.5	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			5	mA
h _{FE}	DC Current Gain	I _C = 3A ; V _{CE} = 3V	750			

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